Model and Design of Improved Current Mode Logic Gates

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Differential and Single-ended



Kirti Gupta Department of Electronics and Communication Bharati Vidyapeeth's College of Engineering New Delhi, Delhi, India

Maneesha Gupta Department of Electronics and Communication Netaji Subhas University of Technology Dwarka, Delhi, India Neeta Pandey Department of Electronics and Communication Delhi Technological University New Delhi, Delhi, India

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Preface

Technological evolution has facilitated the coexistence of digital and analog circuits on a single chip. A single-chip realization has a profound impact on performance, cost, and size. Such chip eases signal acquisition which falls primarily in analog domain and signal processing that is predominately done in the digital domain. The digital circuit design revolves around CMOS due to negligible static power, but it consumes dynamic power which becomes severe at high frequencies and also results in large current spikes during switching event (switching noise). As a consequence, the resolution of analog circuits may decrease; therefore, this issue needs special attention. Alternate logic styles are explored to reduce switching noise which work on keeping power supply current nearly constant during the switching event and/or working with smaller voltage swings. Current mode logic (CML) style is one among these which addresses both the issues and is the main focus of the book.

The book presents the background and a brief review of available literature on CML gates in Chap. 1. The remaining chapters of the book describe newer topologies obtained by modifying the basic parts of CML, namely pull-down network, current source, and load. Chapter 2 is devoted to detailed analysis and design procedure of differential CML and single-ended (PFSCL) gates. The realization of the basic logic gates in differential CML and the single-ended (PFSCL) style is also included. Chapter 3 details the inclusion of triple-tail cell concept in pull-down network of the differential CML gate. This modification leads to lower power supply requirement. It, however, increases the implementation area. The multiple threshold transistor-based triple-tail cell is described next that reduces the overall area requirement. Mathematical formulations for the design-oriented model are elucidated with an intention to develop an understanding of the impact of design and process parameters. The performance of the proposed topologies is illustrated for low-power, high-speed, and power-efficient design cases.

Chapter 4 presents improved dynamic CML (D-CML) gates and self-timed buffer for design of multi-stage applications. Chapter 5 deals with the speed improvement in the CML gates by modifying their load. The load uses the capacitive coupling phenomenon. A complete mathematical model for static parameters and the delay is developed for differential CML and PFSCL gates.

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A systematic design procedure to size the bias current and the transistor's aspect ratio to meet design goals is also presented.

Efficient realization of a logic function in PFSCL style is the aim of Chap. 6. A method to reduce the gate count in comparison with the conventional NOR-based logic function realization is described. A new fundamental cell developed by applying triple-tail cell concept in PFSCL style is presented and analyzed. The use of fundamental cell in realizing various logic functions is discussed, and the overall improvement in terms of gate count, propagation delay, and power is compared with the conventional ones.

Tri-state circuits are the essential elements in bus-organized and programmable logic devices and are explored in Chap. 7. Tri-state circuits in CML style are worked upon in this chapter.

This book details the improved designs of CML gates that are suited to mixed-signal environments. An in-depth analysis and step-by-step design procedure will help the researcher to design a gate for given constraints.

New Delhi, India New Delhi, India New Delhi, India Kirti Gupta Neeta Pandey Maneesha Gupta

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About the Authors

Dr. Kirti Gupta received B.Tech. in Electronics and Communication Engineering from Indira Gandhi Institute of Technology, Delhi in 2002, M. Tech. in Information Technology from School of Information Technology in 2006. She received her Ph.D. in Electronics and Communication Engineering from Delhi Technological University, in 2016. Since 2002, she is with Bharati Vidyapeeth's College of Engineering, New Delhi and is presently serving as Professor in the same institute. A life member of ISTE, and senior member of IEEE, she has published more than 100 research papers in international, national journals and conferences. Her teaching and research interest is in digital VLSI design.

Dr. Neeta Pandey received her M.E. in Microelectronics from Birla Institute of Technology and Sciences, Pilani in 1991 and Ph.D. from Guru Gobind Singh Indraprastha University, Delhi in 2009. She has served in Central Electronics Engineering Research Institute, Pilani, Indian Institute of Technology, Delhi, Priyadarshini College of Computer Science, Noida and Bharati Vidyapeeth's College of Engineering, Delhi in various capacities. At present, she is a professor in the ECE department, Delhi Technological University. Her teaching and research interests include analog and digital VLSI design.

A life member of ISTE, and senior member of IEEE, USA, she has coauthored over 100 papers in international, national journals of repute and conferences.

Dr. Maneesha Gupta is currently a Professor at the Electronics & Communication Engineering Department of the Netaji Subhas University of Technology, India. She received her B.E. in Electronics & Communication Engineering from the Government Engineering College, Jabalpur in 1981, M.E. in Electronics & Communication Engineering from the same university in 1983, and her PhD. in Electronics Engineering (Analysis, Synthesis & Applications of Switched Capacitor Circuits) from the Indian Institute of Technology, Delhi in 1990.

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Her teaching and research interests include switched capacitor circuits and analog signal processing. Dr. Gupta has co-authored over 150 research papers in the above areas in various international/national journals and conferences.